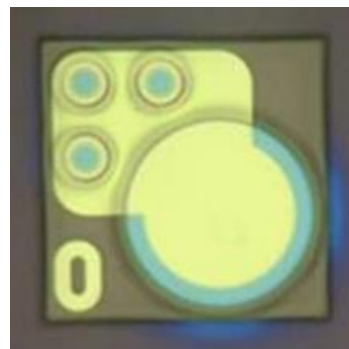


#### Features

- : 850nm wavelength range
- : 10mW VCSEL
- : Multi\_mode beam profile
- : Multiple mesa type
- : High reliability
- : Other configurations available on request

#### Description



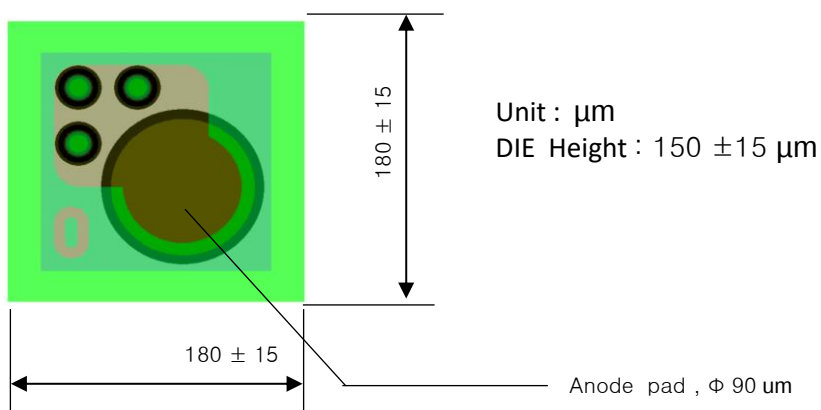
#### Applications

- : Consumer electronics
- : Safety sensor
- : Illumination light source
- : Proximity sensor

#### Absolute Maximum Ratings

| Parameter                  | Rating       |
|----------------------------|--------------|
| Storage Temperature        | -40 to 85 °C |
| Operating Temperature      | -10 to 60 °C |
| Continuous Forward Current | 20mA         |

#### Dimensions



**Electro-Optics Characteristics (  $T_a=25^{\circ}\text{C}$  unless otherwise stated)**

| Parameters                      | Symbol                      | Specified |      |      | Unit                   | Test Conditions                             |
|---------------------------------|-----------------------------|-----------|------|------|------------------------|---------------------------------------------|
|                                 |                             | Min.      | Typ. | Max. |                        |                                             |
| Threshold Current               | $I_{th}$                    |           | 3.0  |      | mA                     | CW                                          |
| $I_{th}$ Temperature Variation  | $\Delta I_{th}$             |           | 2.0  |      | mA                     | $T_a = -10$ to $70^{\circ}\text{C}$         |
| Slope Efficiency                | $\eta$                      |           | 1.0  |      | W/A                    | $I_f = 13$ mA                               |
| Optical Output Power            | $P_o$                       |           | 10   |      | mW                     | $I_f = 13$ mA                               |
| Peak Wavelength                 | $\lambda_p$                 | 840       | 850  | 860  | nm                     | $I_f = 13$ mA                               |
| $\lambda$ Temperature Variation | $\Delta \lambda / \Delta T$ |           | 0.06 |      | nm/ $^{\circ}\text{C}$ | $T_a = -10$ to $70^{\circ}\text{C}$ at 13mA |
| Beam Divergence                 | $\Theta$                    |           | 20   |      | $^{\circ}$             | $P_o = 10$ mW (FWHM)                        |
| Operating Voltage               | $V_f$                       |           | 2.2  | 2.5  | V                      | $I_f = 13$ mA                               |
| Breakdown Voltage               | $V_b$                       | -10       |      |      | V                      |                                             |
| Dynamic Resistance              | $R_d$                       |           | 30   |      | Ohm                    | $I_f = 13$ mA                               |

**Notes**

\* These specifications are subject to change without notice.

**ATTENTION**

CAUTION  
PRECAUTIONS  
FOR HANDLING  
ELECTRONIC  
COMPONENTS

**NOTICE**

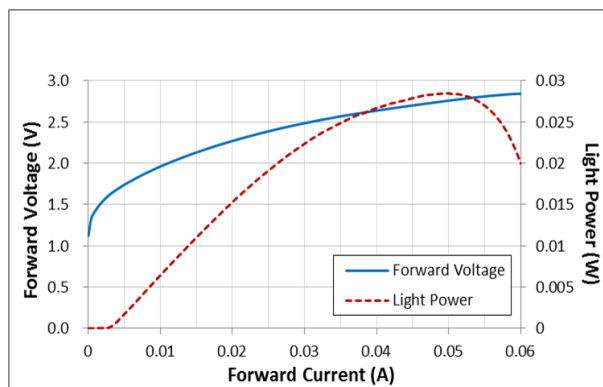
The inherent design of this component causes it to be sensitive to electrostatic discharge(ESD). To prevent ESD-induced damage and/or degradation to equipment, take normal ESD precautions when handling this product

**DANGER**

The VCSEL is a class IIIb laser and should be treated as a potential eye hazard. Due to the size of the component, the applicable warning logotype, aperture label, and certification / identification label cannot be placed on the component itself.

#### Characteristics Curves

##### LIV Curve

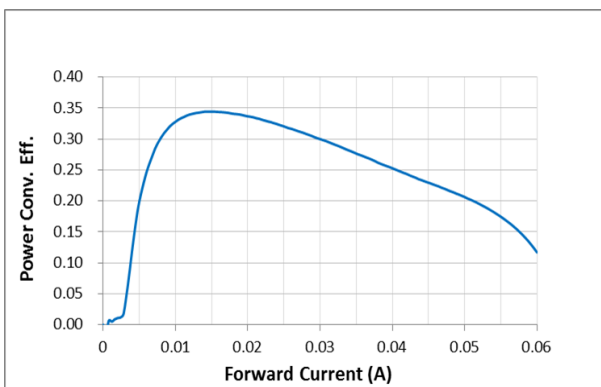


Test PKG sample : To-Can type, To-46

Test condition :

CW Mode : IF step interval 2mA, Delay time 2msec

##### Power conversion efficiency



Test PKG sample : To-Can type, To-46

Test condition :

CW Mode : IF step interval 2mA, Delay time 2msec



**Optowell Co., Ltd.**

**HV85-0010M1** Pre 1.0

10mW 850 nm VCSEL Chip

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